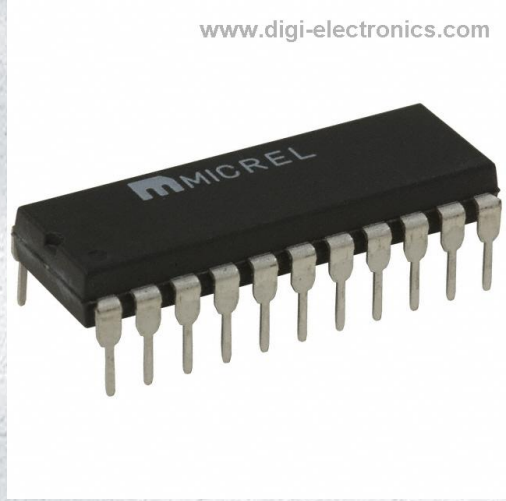
MIC5801YN Datasheet



DiGi Electronics Part Number	MIC5801YN-DG
Manufacturer	Microchip Technology
Manufacturer Product Number	MIC5801YN
Description	IC PWR DRIVER BIPOLAR 1:1 22DIP
Detailed Description	Power Switch/Driver 1:1 Bipolar 500mA 22-PDIP

https://www.DiGi-Electronics.com

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MIC5801YN	Microchip Technology
Series:	Packaging:
-	Tube
Part Status:	Switch Type:
Obsolete	Latched Driver
Number of Outputs:	Ratio - Input:Output:
8	1:1
Output Configuration:	Output Type:
Low Side	Bipolar
Interface:	Voltage - Load:
Strobe, Parallel	50V (Max)
Voltage - Supply (Vcc/Vdd):	Current - Output (Max):
-	500mA
Rds On (Typ):	Input Type:
-	-
Features:	Fault Protection:
-	-
Operating Temperature:	Mounting Type:
-40°C ~ 85°C (TA)	Through Hole
Supplier Device Package:	Package / Case:
22-PDIP	22-DIP (0.400", 10.16mm)
Base Product Number:	
MIC5801	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8542.39.0060	

MIC5800/1

4/8-Bit Parallel-Input Latched Drivers

Features

- 4.4 MHz Minimum Data Input Rate
- High-Voltage, High-Current Sink Outputs
- Output Transient Protection
- CMOS, PMOS, NMOS, and TTL Compatible Inputs
- Internal Pull-Down Resistors
- Low-Power CMOS Latches

General Description

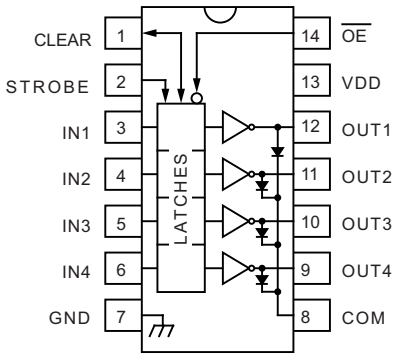
The MIC5800 and MIC5801 latched drivers are high-voltage, high-current integrated circuits comprised of four or eight CMOS data latches, a bipolar Darlington transistor driver for each latch, and CMOS control circuitry for the common CLEAR, STROBE, and OUTPUT ENABLE functions.

The bipolar/MOS combination provides an extremely low-power latch with maximum interface flexibility. MIC5800 contains four latched drivers; MIC5801 contains eight latched drivers.

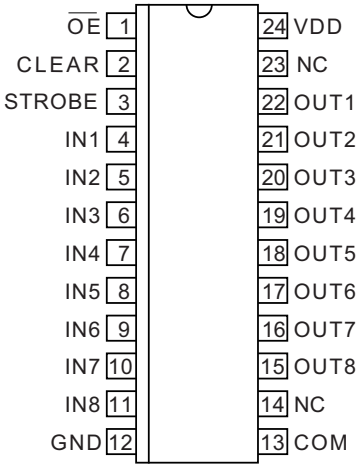
Data input rates are greatly improved in these devices. With a 5V supply, they will typically operate at better than 5 MHz. With a 12V supply, significantly higher speeds are obtained. The CMOS inputs are compatible with standard CMOS, PMOS, and NMOS circuits. TTL or DTL circuits may require the use of appropriate pull-up resistors. The bipolar outputs are suitable for use with relays, solenoids, stepping motors, LED or incandescent displays, and other high-power loads. Both units have open-collector outputs and integral diodes for inductive load transient suppression. The output transistors are capable of sinking 500 mA and will sustain at least 50V in the OFF state. Because of limitations on package power dissipation, the simultaneous operation of all drivers at maximum rated current can only be accomplished by a reduction in duty cycle. Outputs may be connected in parallel for higher load current capability.

Package Types

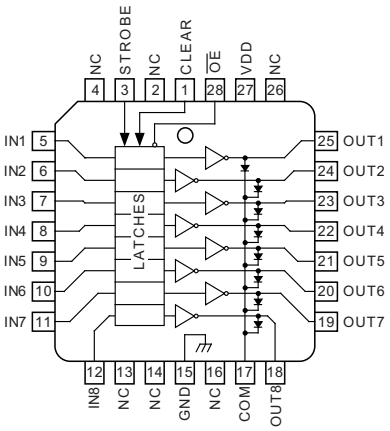
MIC5800YM
14-Lead SOIC (M)
(Top View)



MIC5801YWM
24-Lead SOIC (WM)
(Top View)

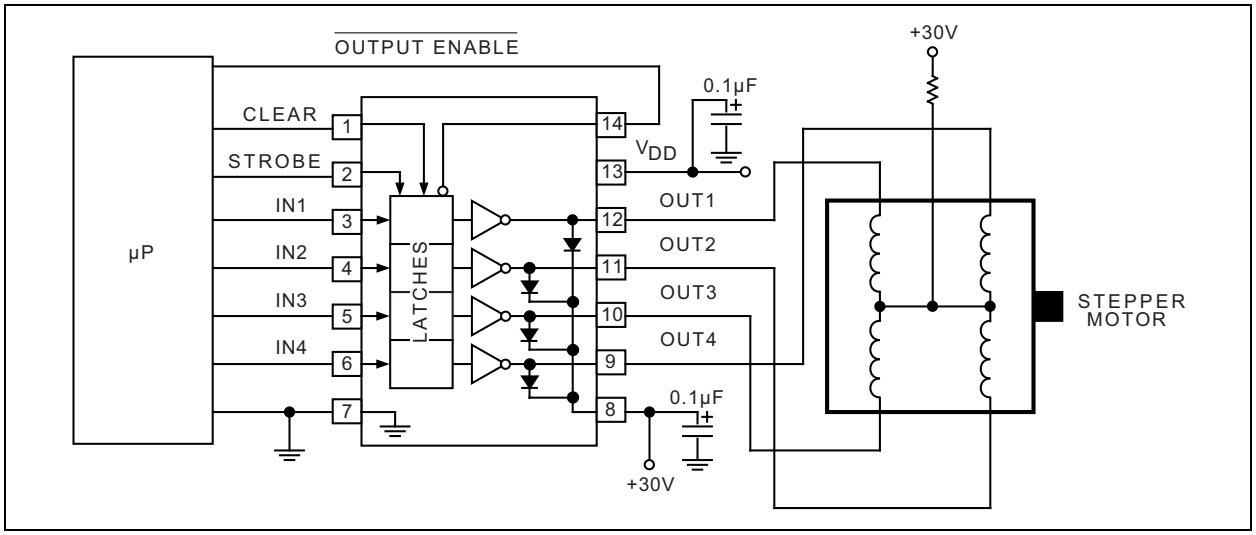


MIC5801YV
28-Lead PLCC (V)
(Top View)

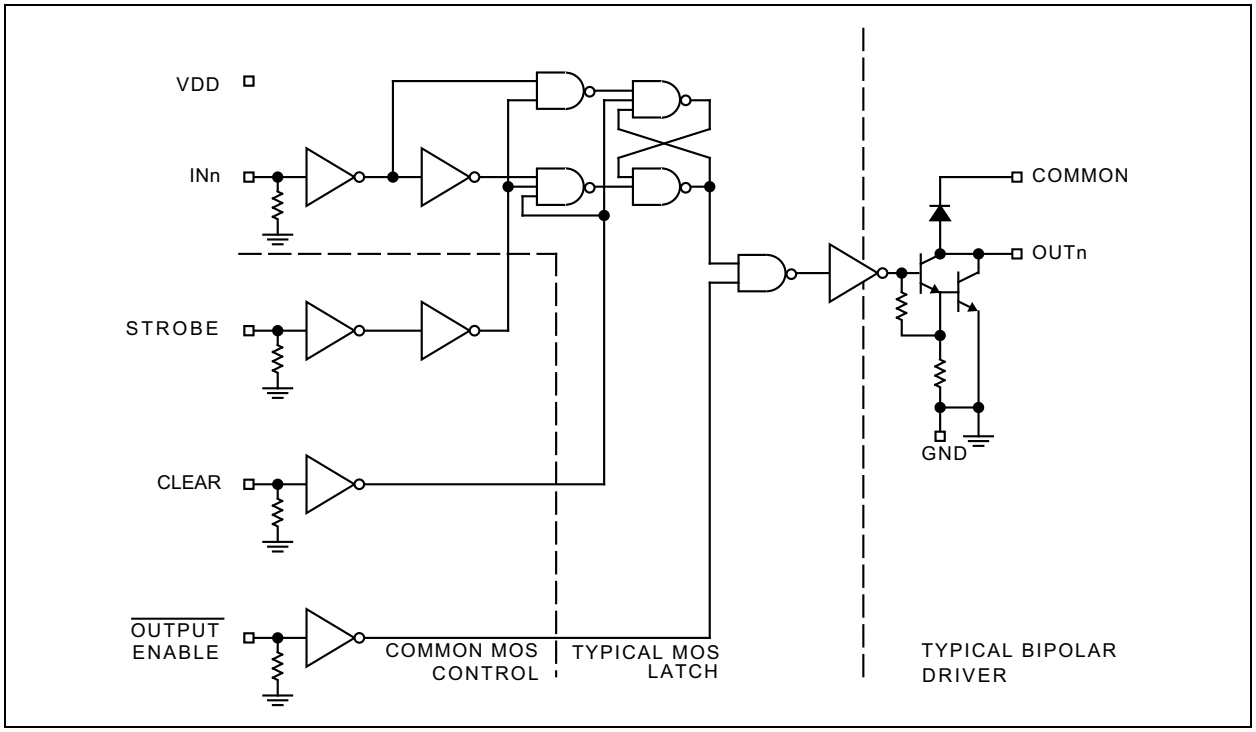


MIC5800/1

Typical Application Circuit



Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Output Voltage (V_{CE}) ..... +50V
Supply Voltage (V_{DD}) ..... +15V
Input Voltage Range (V_{IN}) ..... –0.3V to V_{DD} + 0.3V
Continuous Collector Current (I_C) ..... 500 mA
ESD Rating (Note 1) ..... ESD Sensitive

Operating Ratings ††

Package Power Dissipation (P_D)
MIC5800 SOIC 1.0W
Derate above T_A = +25°C ..... 8.5 mW/°C
MIC5801 PLCC 2.25W
Derate above T_A = +25°C ..... 18.2 mW/°C
MIC5801 Wide SOIC 1.4W
Derate above T_A = +25°C ..... 11 mW/°C

† Notice: Exceeding the absolute maximum ratings may damage the device.

†† Notice: The device is not guaranteed to function outside its operating ratings.

Note 1: Microchip CMOS devices have input-static protection, but are susceptible to damage when exposed to extremely high static electrical charges.

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{DD} = 5V, T_A = +25°C, V_A ≤ +85°C unless otherwise noted. Note 1

Parameter	Sym.	Min.	Typ.	Max.	Units	Conditions
Output Leakage Current	I_{CEX}	—	—	50	µA	V_{CE} = 50V, T_A = +25°C
		—	—	100		V_{CE} = 50V, T_A = +70°C
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	0.9	1.1	V	I_C = 100 mA
		—	1.1	1.3		I_C = 200 mA
		—	1.3	1.6		I_C = 350 mA, V_{DD} = 7.0V
Input Voltage (Low)	$V_{IN(0)}$	—	—	1.0	V	—
Input Voltage (High)	$V_{IN(1)}$	10.5	—	—	V	V_{DD} = 12V
		8.5	—	—		V_{DD} = 10V
		3.5	—	—		V_{DD} = 5V, Note 2
Input Resistance	R_{IN}	50	200	—	kΩ	V_{DD} = 12V
		50	300	—		V_{DD} = 10V
		50	600	—		V_{DD} = 5V
Supply Current ON (Each Stage)	$I_{DD(ON)}$	—	1.0	2.0	mA	V_{DD} = 12V, Outputs Open
		—	0.9	1.7		V_{DD} = 10V, Outputs Open
		—	0.7	1.0		V_{DD} = 5V, Outputs Open
Supply Current OFF (Total)	$I_{DD(OFF)}$	—	—	200	µA	V_{DD} = 12V, Outputs Open, Inputs = 0V
		—	50	100		V_{DD} = 5V, Outputs Open, Inputs = 0V

Note 1: Specification for packaged product only.

2: Operation of these devices with standard TTL or DTL may require the use of appropriate pull-up resistors to ensure a minimum logic “1”.

ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: V_{DD} = 5V, T_A = +25°C, V_A ≤ +85°C unless otherwise noted. Note 1						
Parameter	**Sym.**	**Min.**	**Typ.**	**Max.**	**Units**	**Conditions**
Clamp Diode Leakage Current	I_R	—	—	50	µA	V_R = 50V, T_A = +25°C
		—	—	100		V_R = 50V, T_A = +70°C
Clamp Diode Forward Voltage	V_F	—	1.7	2.0	V	I_F = 350 mA

Note 1: Specification for packaged product only.

2: Operation of these devices with standard TTL or DTL may require the use of appropriate pull-up resistors to ensure a minimum logic “1”.

TRUTH TABLE

IN_N	**Strobe**	**Clear**	**/OE**	**OUT_N**	
				t – 1	**t**
0	1	0	0	X	OFF
1	1	0	0	X	ON
X	X	1	X	X	OFF
X	X	X	1	X	OFF
X	0	0	0	ON	ON
X	0	0	0	OFF	OFF

Legend: X = Irrelevant; t – 1 = Previous output state; t = Present output state.

Information present at an input is transferred to its latch when the STROBE is high. A high CLEAR input will set all latches to the output OFF condition regardless of the data or STROBE input levels. A high /OE will set all outputs to the off condition, regardless of any other input conditions. When the /OE is low, the outputs depend on the state of their respective latches.

TEMPERATURE SPECIFICATIONS

Parameters	**Sym.**	**Min.**	**Typ.**	**Max.**	**Units**	**Conditions**
Temperature Ranges						
Storage Temperature Range	T_S	–65	—	+125	°C	—
Operating Temperature Range	T_A	–40	—	+85	°C	—

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +125°C rating. Sustained junction temperatures above +125°C can impact the device reliability.

2.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 2-1 and Table 2-2.

TABLE 2-1: MIC5800 PIN FUNCTION TABLE

Pin Number	Pin Name	Description
1	CLEAR	Resets all latches and turns all outputs OFF (open).
2	STROBE	Input strobe pin. Loads output latches when high.
3, 4, 5, 6	IN_N	Parallel inputs, 1 through 4.
7	GND	Logic and Output Ground pin.
8	COM	Transient suppression diode common cathode pin.
9, 10, 11, 12	OUT_N	Parallel outputs, 4 through 1.
13	VDD	Logic Supply Voltage.
14	/OE	Output Enable. When low, outputs are active. When high, outputs are inactive and device is reset from a fault condition. An undervoltage condition emulates a high OE input.

TABLE 2-2: MIC5801 PIN FUNCTION TABLE

Pin Number SOIC	Pin Number PLCC	Pin Name	Description
1	28	/OE	Output Enable. When low, outputs are active. When high, outputs are inactive and device is reset from a fault condition. An undervoltage condition emulates a high OE input.
2	1	CLEAR	Resets all latches and turns all outputs OFF (open).
3	3	STROBE	Input strobe pin. Loads output latches when high.
4, 5, 6, 7, 8, 9, 10, 11	5, 6, 7, 8, 9, 10, 11, 12	IN_N	Parallel inputs, 1 through 8.
12	15	GND	Logic and Output Ground pin.
13	17	COM	Transient suppression diode common cathode pin.
14, 23	2, 4, 13, 14, 16, 26	NC	No Connection. Leave floating.
15, 16, 17, 18, 19, 20, 21, 22	18, 19, 20, 21, 22, 23, 24, 25	OUT_N	Parallel outputs, 8 through 1.
24	27	VDD	Logic Supply Voltage.

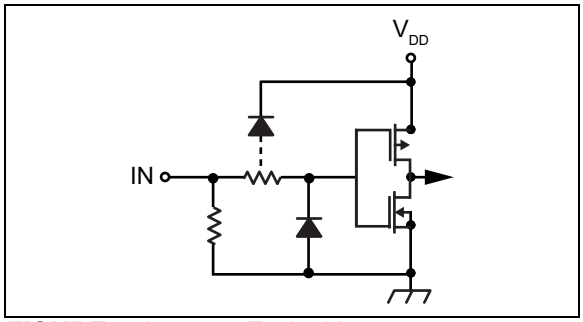


FIGURE 2-1: *Typical Input.*

3.0 TIMING

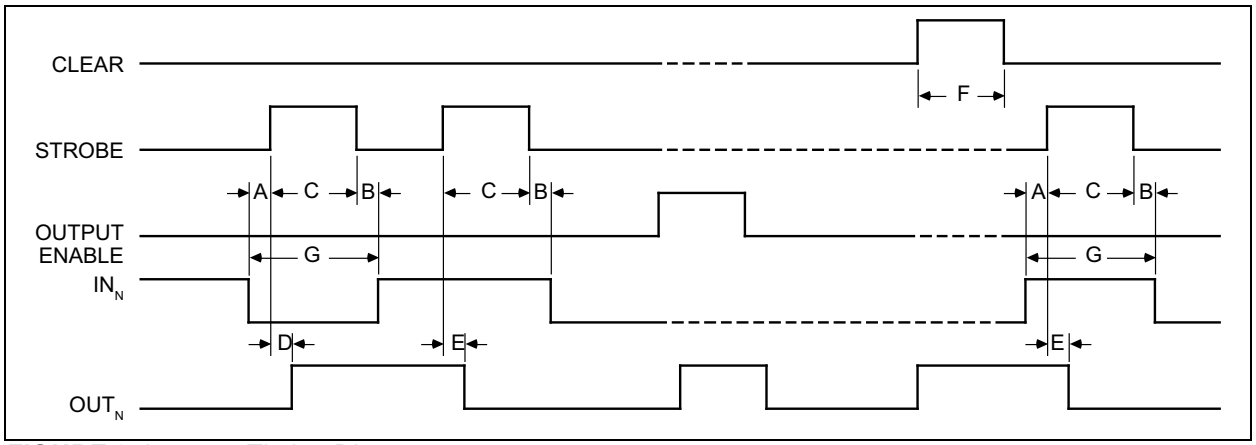


FIGURE 3-1: *Timing Diagram.*

TABLE 3-1: TIMING CONDITIONS

Characteristics: T_A = +25°C; Logic levels are V_{DD} and Ground; V_{DD} = 5V.			
Condition	**Min.**	**Typ.**	**Max.**
A. Minimum data active time before strobe enabled (data set-up time)	50 ns	—	—
B. Minimum data active time after strobe disabled (data hold time)	50 ns	—	—
C. Minimum strobe pulse width	125 ns	—	—
D. Typical time between strobe activation and output on to off transition	—	500 ns	—
E. Typical time between strobe activation and output off to on transition	—	500 ns	—
F. Minimum clear pulse width	300 ns	—	—
G. Minimum data pulse width	225 ns	—	—

4.0 TYPICAL APPLICATIONS

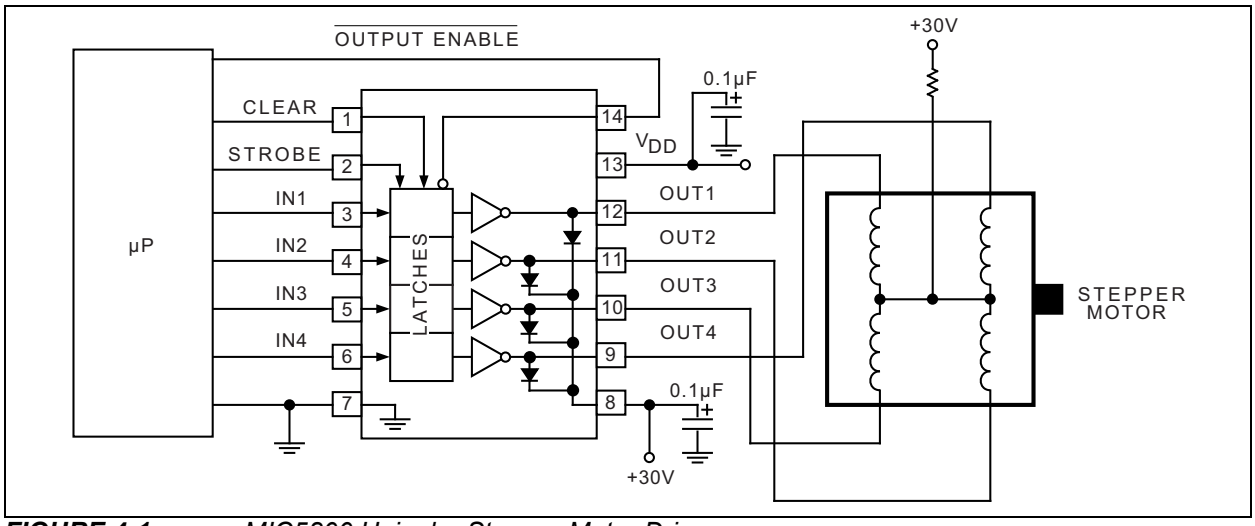


FIGURE 4-1: *MIC5800 Unipolar Stepper-Motor Drive.*

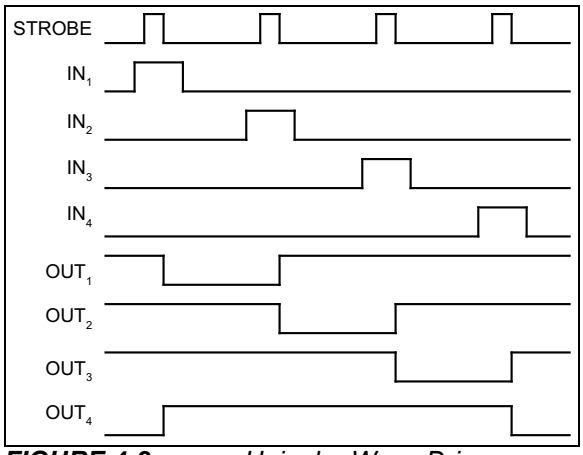


FIGURE 4-2: *Unipolar Wave Drive.*

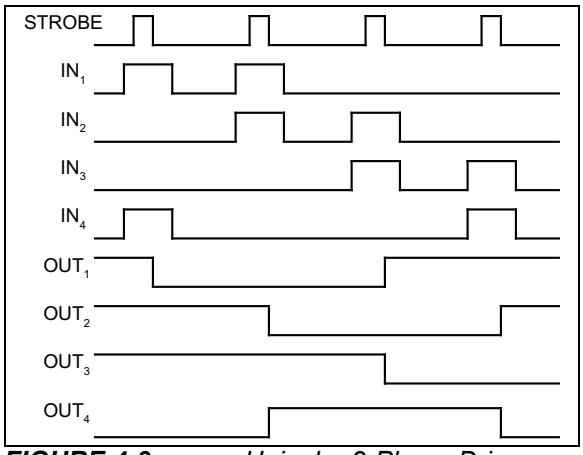


FIGURE 4-3: *Unipolar 2-Phase Drive.*

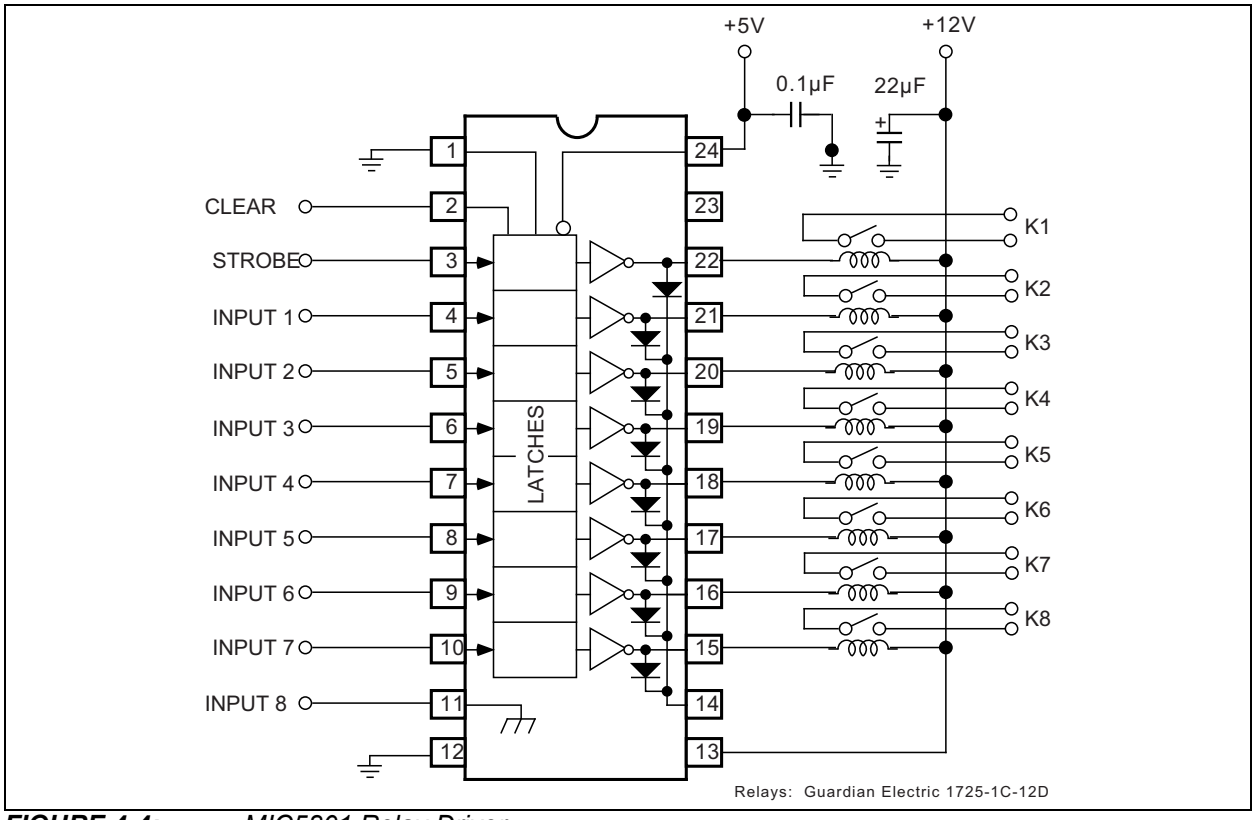


FIGURE 4-4: *MIC5801 Relay Driver.*

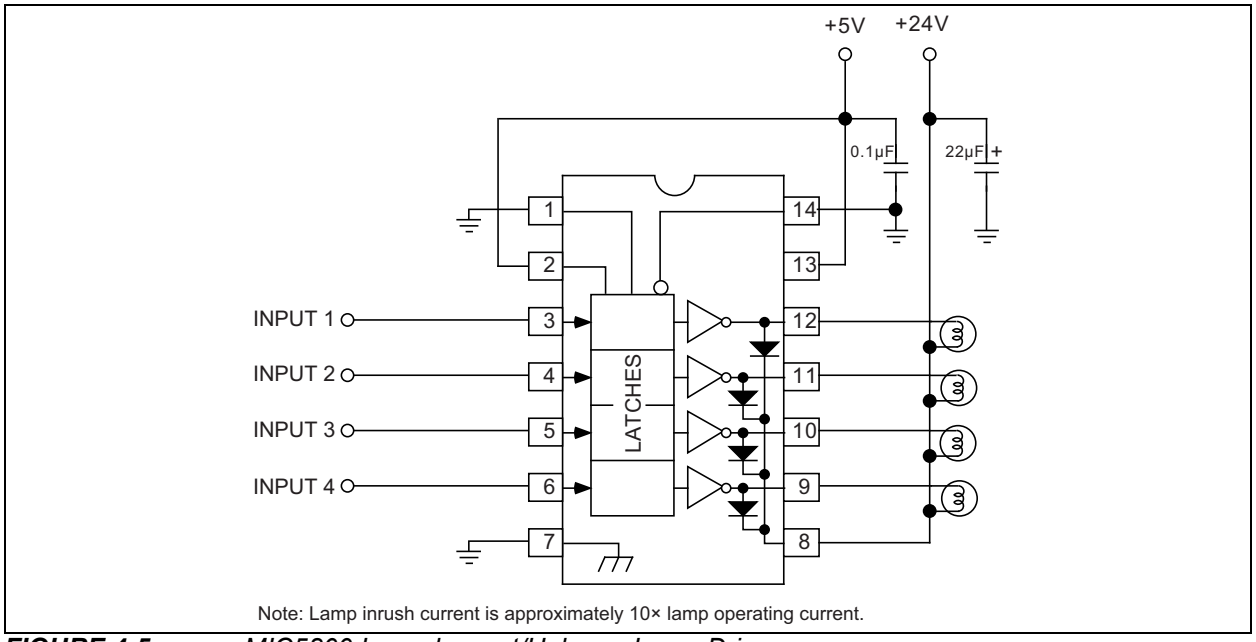
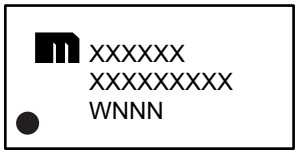


FIGURE 4-5: *MIC5800 Incandescent/Halogen Lamp Driver.*

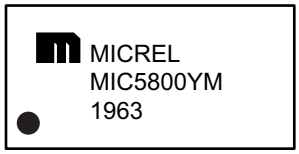
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

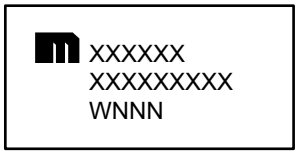
14-Lead SOIC*



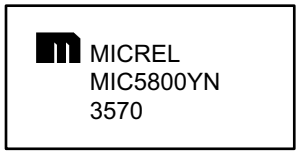
Example



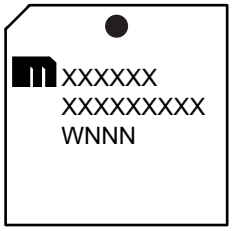
14-Lead PDIP*



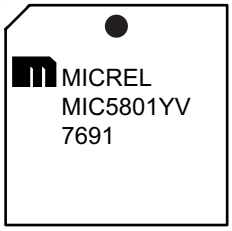
Example



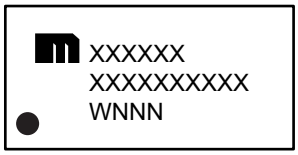
28-Lead PLCC*



Example



24-Lead SOICW*



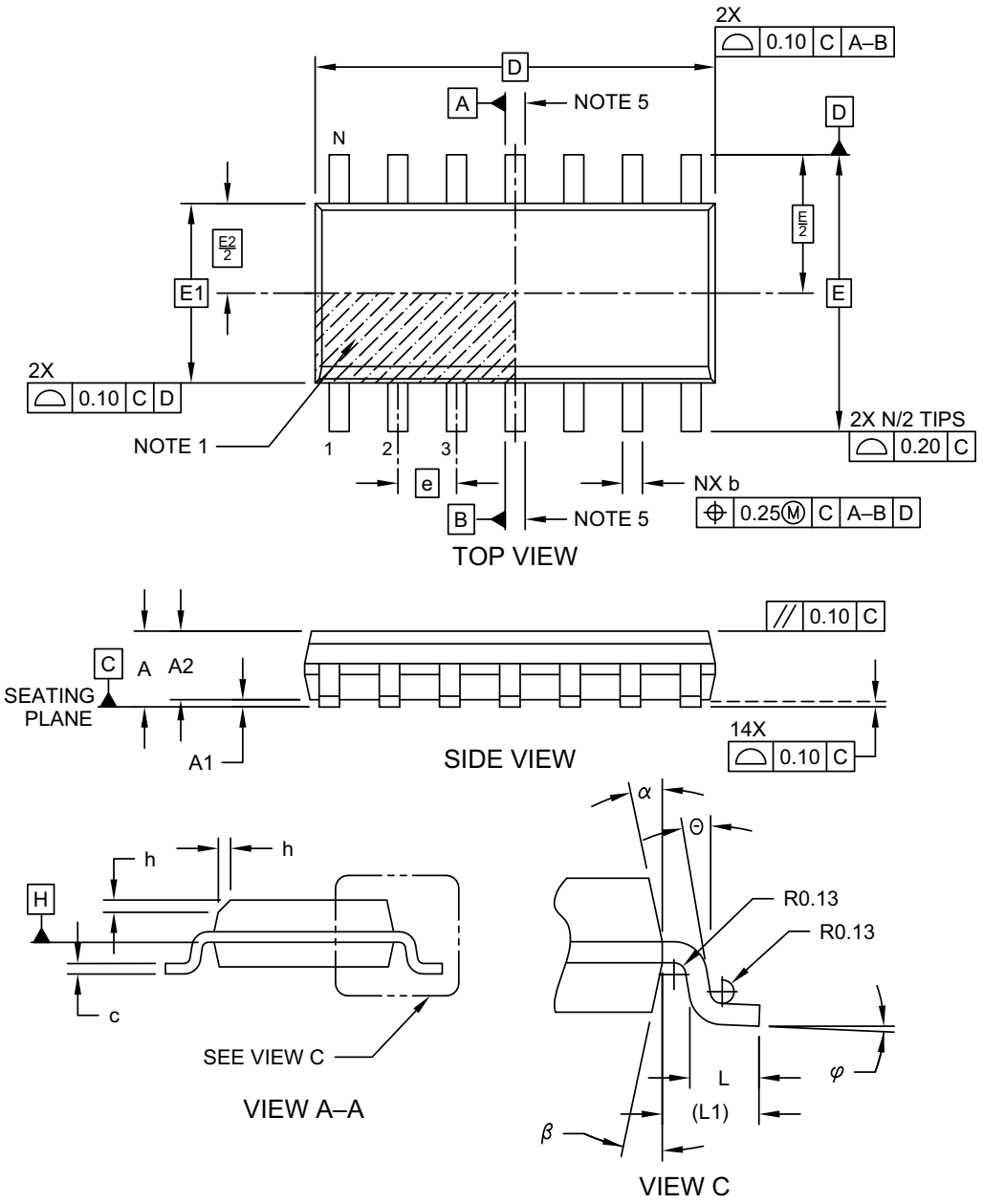
Example

Legend:	XX...X	Product code or customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week ‘01’)
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC® designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.
	●, ▲, ▼	Pin one index is identified by a dot, delta up, or delta down (triangle mark).
Note:		In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo.
		Underbar (_) and/or Overbar (¯) symbol may not be to scale.

14-Lead Plastic Small Outline SOIC Package Outline and Recommended Land Pattern

14-Lead Plastic Small Outline (D3X, UEB, M5B, UEB) - Narrow, 3.90 mm Body [SOIC]
Atmel Legacy Global Package Code SVQ

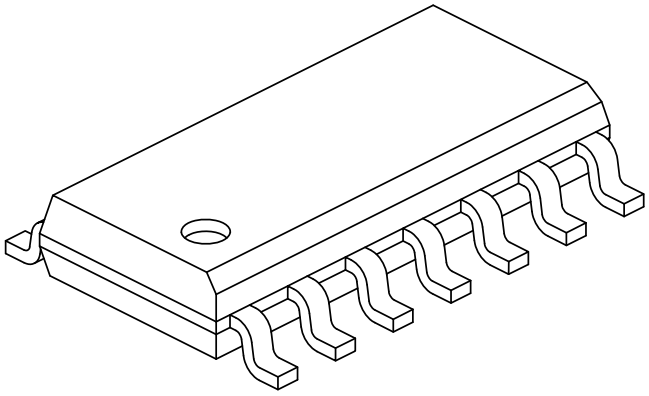
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing No. C04-065-D3X Rev D

14-Lead Plastic Small Outline (D3X, UEB, M5B, UEB) - Narrow, 3.90 mm Body [SOIC]
Atmel Legacy Global Package Code SVQ

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		14	
Pitch	e		1.27 BSC	
Overall Height	A	-	-	1.75
Molded Package Thickness	A2	1.25	-	-
Standoff §	A1	0.10	-	0.25
Overall Width	E		6.00 BSC	
Molded Package Width	E1		3.90 BSC	
Overall Length	D		8.65 BSC	
Chamfer (Optional)	h	0.25	-	0.50
Foot Length	L	0.40	-	1.27
Footprint	L1		1.04 REF	
Lead Angle	Θ	0°	-	-
Foot Angle	φ	0°	-	8°
Lead Thickness	c	0.10	-	0.25
Lead Width	b	0.31	-	0.51
Mold Draft Angle Top	α	5°	-	15°
Mold Draft Angle Bottom	β	5°	-	15°

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. § Significant Characteristic
3. Dimension D does not include mold flash, protrusions or gate burrs, which shall not exceed 0.15 mm per end. Dimension E1 does not include interlead flash or protrusion, which shall not exceed 0.25 mm per side.
4. Dimensioning and tolerancing per ASME Y14.5M

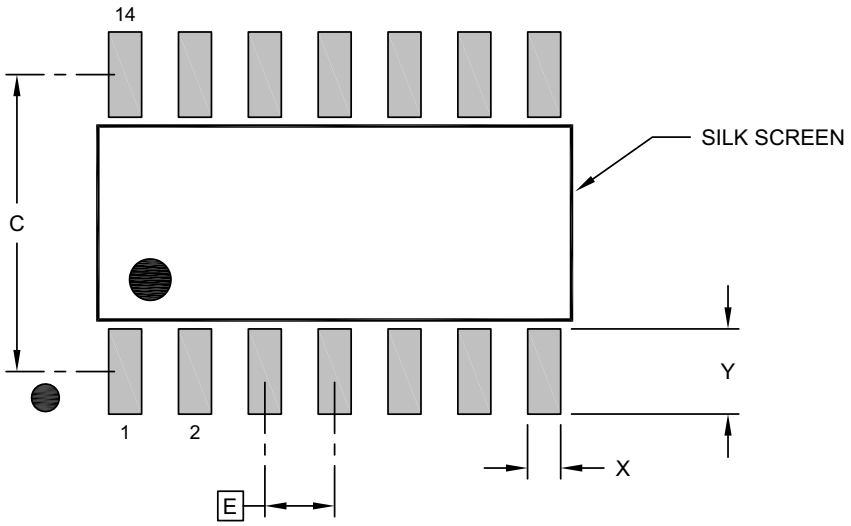
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

   REF: Reference Dimension, usually without tolerance, for information purposes only.
5. Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-065-D3X Rev D Sheet 2 of 2

14-Lead Plastic Small Outline (D3X, UEB, M5B, UEB) - Narrow, 3.90 mm Body [SOIC]
Atmel Legacy Global Package Code SVQ

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		1.27 BSC	
Contact Pad Spacing	C		5.40	
Contact Pad Width (X14)	X			0.60
Contact Pad Length (X14)	Y			1.55

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

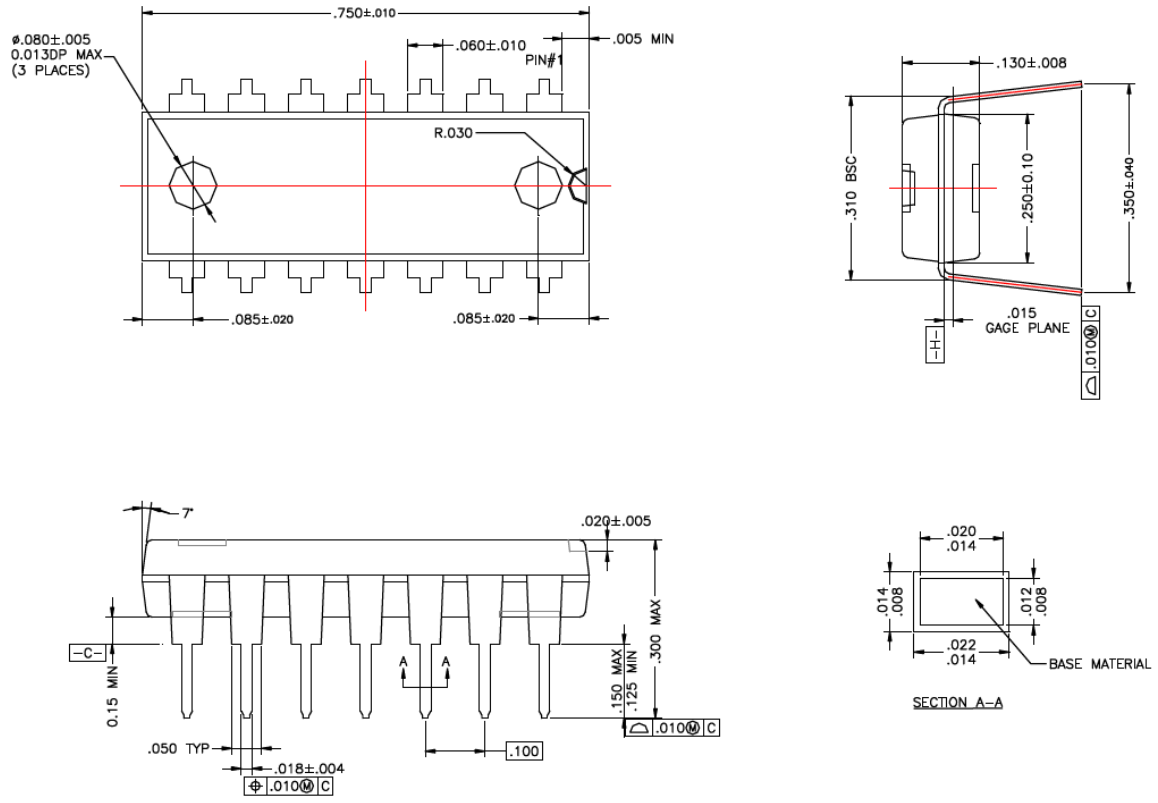
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2065-D3X Rev D

14-Lead PDIP Package Outline and Recommended Land Pattern

TITLE
14 LEAD PDIP PACKAGE OUTLINE & RECOMMENDED LAND PATTERN

DRAWING #	PDIP-14LD-PL-1	**UNIT**	INCH
LEAD FRAME	Copper	**LEAD FINISH**	Matte Tin

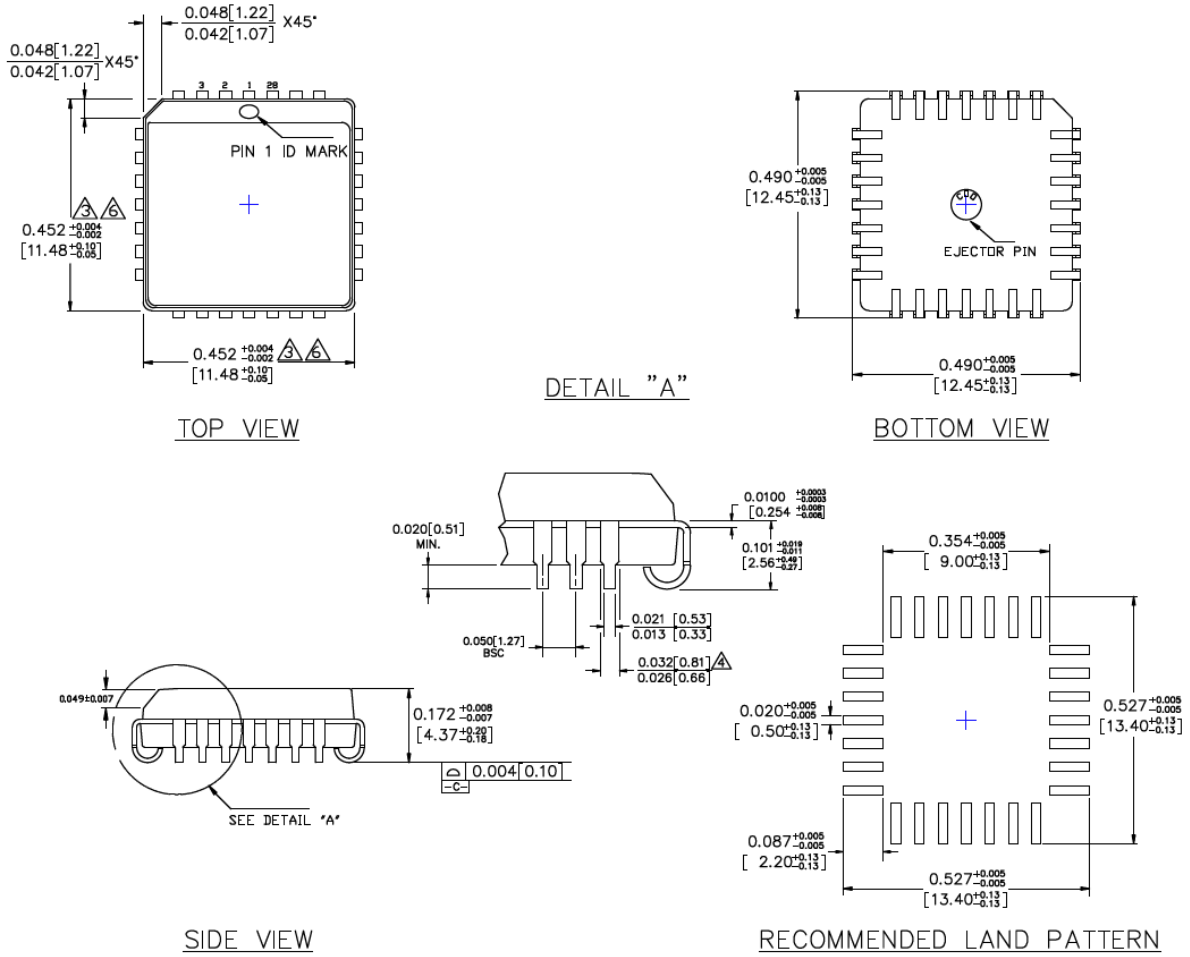


Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging.

28-Lead PLCC Package Outline and Recommended Land Pattern

TITLE
28 LEAD PLCC PACKAGE OUTLINE & RECOMMENDED LAND PATTERN

DRAWING #	PLCC-28LD-PL-1	UNIT	INCH [MM]



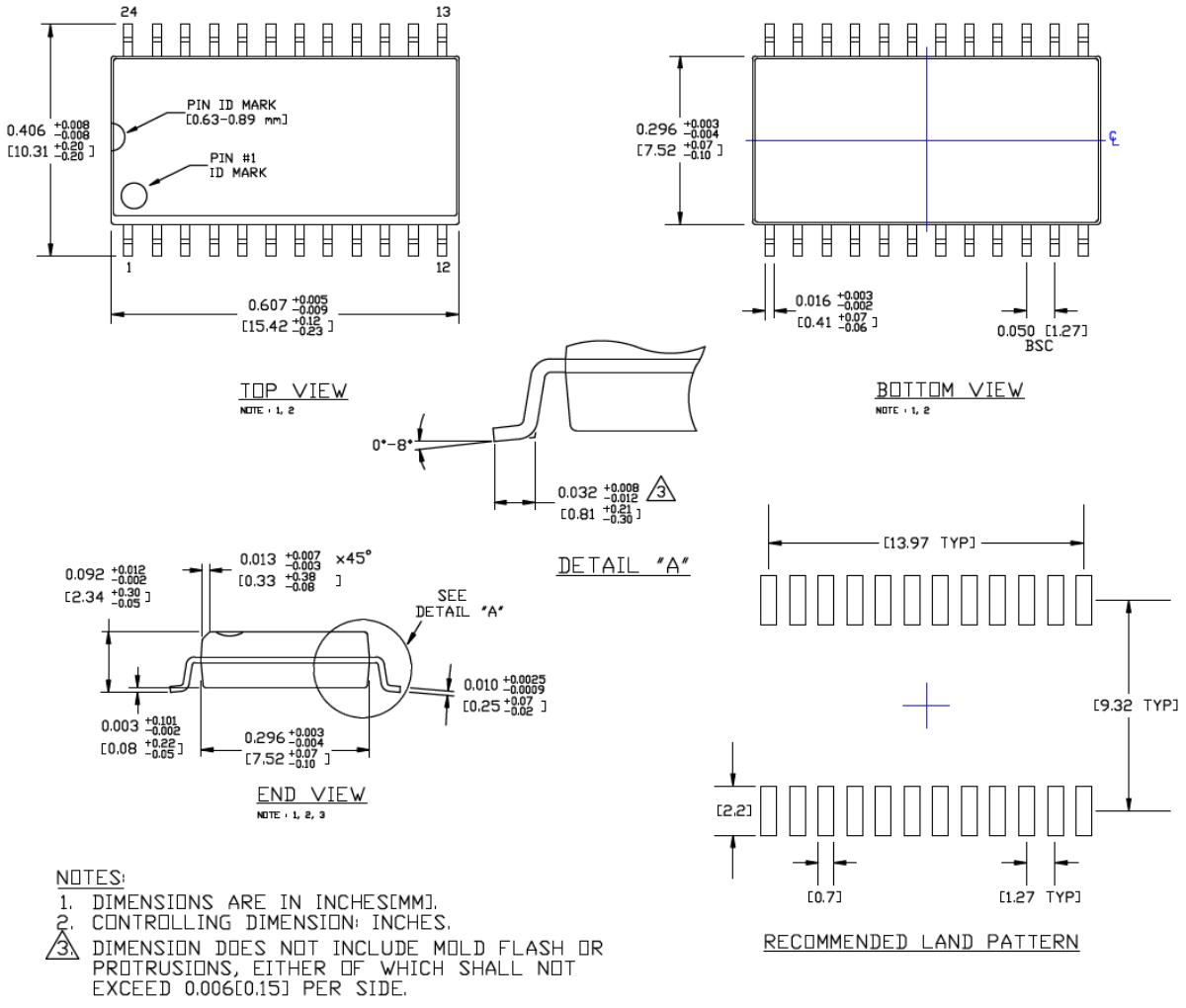
NOTES:
1. DIMENSIONS ARE IN INCHES [MM].
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSION DOES NOT INCLUDE MOLD FLASH OR PROTRUSIONS, EITHER OF WHICH SHALL NOT EXCEED 0.008 [0.203].
4. LEAD DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION.
5. MAXIMUM AND MINIMUM SPECIFICATIONS ARE INDICATED AS FOLLOWS : MAX/MIN
6. PACKAGE TOP DIMENSION MAY BE SLIGHTLY SMALLER THAN BOTTOM DIMENSION.

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging.

24-Lead SOICW Package Outline and Recommended Land Pattern

TITLE
24 LEAD SOICW PACKAGE OUTLINE & RECOMMENDED LAND PATTERN

DRAWING #	SOICW-24LD-PL-1	UNIT	INCH [MM]



NOTES:
1. DIMENSIONS ARE IN INCHES[MM].
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSION DOES NOT INCLUDE MOLD FLASH OR PROTRUSIONS, EITHER OF WHICH SHALL NOT EXCEED 0.006[0.15] PER SIDE.

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging.

NOTES:

APPENDIX A: REVISION HISTORY

Revision A (April 2019)

- Converted Micrel document MIC5800/1 to Microchip data sheet template DS20006184A.
- Minor grammatical text changes throughout.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

Device	X	XX	-XX
Part No.	Junction Temp. Range	Package	Media Type

Device:	MIC5800:	4-Bit Parallel-Input, High-Voltage, High-Current Latched Driver
	MIC5801:	8-Bit Parallel-Input, High-Voltage, High-Current Latched Driver
Junction Temperature Range:	Y =	–40°C to +85°C, Industrial
Package:	M =	14-Lead SOIC (MIC5800)
	N =	14-Lead PDIP (MIC5800)
	V =	28-Lead PLCC (MIC5801)
	WM =	24-Lead Wide SOIC (MIC5801)
Media Type:	<blank>=	54/Tube (M, MIC5800)
	<blank>=	25/Tube (N, MIC5800)
	<blank>=	38/Tube (V, MIC5801)
	<blank>=	31/Tube (WM, MIC5801)
	TR =	750/Reel (V, MIC5801)
	TR =	1,000/Reel (WM, MIC5801)
	TR =	2,500/Reel (M, MIC5800)

Examples:

a) MIC5800YM:	MIC5800, –40°C to +85°C Temperature Range, 14-Lead SOIC, 54/Tube
b) MIC5800YM-TR:	MIC5800, –40°C to +85°C Temperature Range, 14-Lead SOIC, 2,500/Reel
c) MIC5800YN:	MIC5800, –40°C to +85°C Temperature Range, 14-Lead PDIP, 25/Tube
d) MIC5801YV:	MIC5801, –40°C to +85°C Temperature Range, 28-Lead PLCC, 38/Tube
e) MIC5801YV-TR:	MIC5801, –40°C to +85°C Temperature Range, 28-Lead PLCC, 750/Reel
f) MIC5801YWM:	MIC5801, –40°C to +85°C Temperature Range, 24-Lead Wide SOIC, 31/Tube
g) MIC5801YWM-TR:	MIC5801, –40°C to +85°C Temperature Range, 24-Lead Wide SOIC, 1,000/Reel

Note 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.

NOTES:

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.

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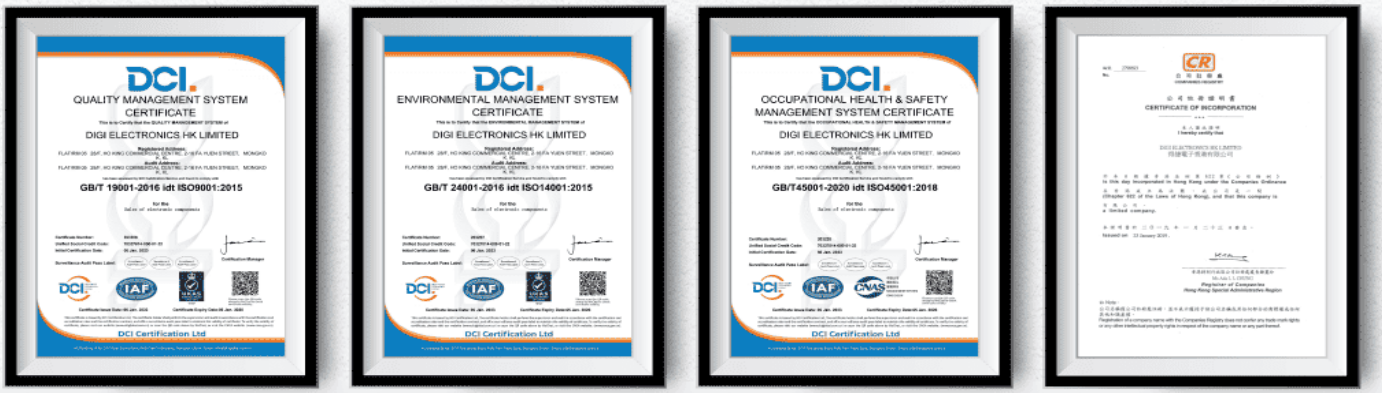

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